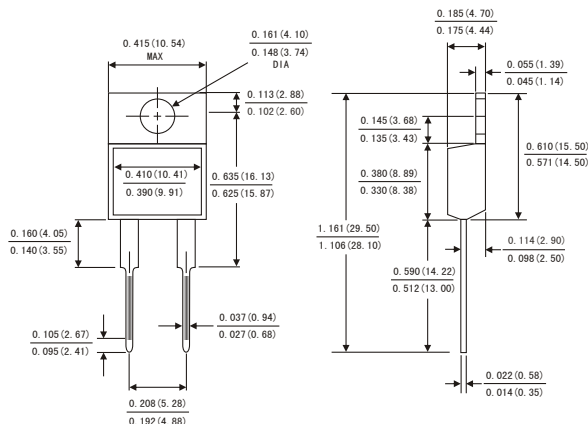


FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss ,high efficiency
- High current capability ,Low forward voltage drop
- Single rectifier construction
- High surge capability
- For use in low voltage ,high frequency inverters, free wheeling ,and polarity protection applications
- High temperature soldering guaranteed:260°C/10 seconds, 0.25"(6.35mm)from case
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



TO-220AC



MECHANICAL DATA

- Case: JEDEC TO-220AC molded plastic body
- Terminals: Lead solderable per MIL-STD-750,method 2026
- Polarity: As marked
- Mounting Position: Any
- Weight: 0.08ounce, 2.24 gram

Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified ,Single phase ,half wave ,resistive or inductive load. For capacitive load,derate by 20%.)

	Symbols	SR 620	SR 630	SR 640	SR 650	SR 660	SR 680	SR 6A0	SR 6150	SR 6200	Units
Maximum repetitive peak reverse voltage	VRRM	20	30	40	50	60	80	100	150	200	Volts
Maximum RMS voltage	VRMS	14	21	28	35	42	57	71	105	140	Volts
Maximum DC blocking voltage	VBC	20	30	40	50	60	80	100	150	200	Volts
Maximum average forward rectified current 0.375"(9.5mm) lead length(see fig.1)	I(AV)	6.0									Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method at rated Tj)	IFSM	150.0									Amps
Maximum instantaneous forward voltage at 6.0 A(Note 1)	VF	0.60			0.75		0.85		0.90	0.95	Volts
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	Ta=25°C Ta=100°C	IR	0.5								mA
			50			25					
Typical junction capacitance(Note 3)	CJ	500				400					pF
Typical thermal resistance (Note 2)	RθJA RθJL	25.0 8.0									°C/W
Operating junction temperature range	TJ	-65 to+125				-65 to+150					°C
Storage temperature range	TSTG	-65 to+150									°C

Notes: 1.Pulse test: 300 μ s pulse width,1% duty cycle

2.Thermal resistance from junction to lead vertical P.C.B. mounted , 0.375"(9.5mm)lead length

3.Measured at 1MHz and reverse voltage of 4.0volts

RATINGS AND CHARACTERISTIC CURVES SR620 THRU SR6200(SINGLE CHIP)

FIG.1-FORWARD CURRENT DERATING CURVE

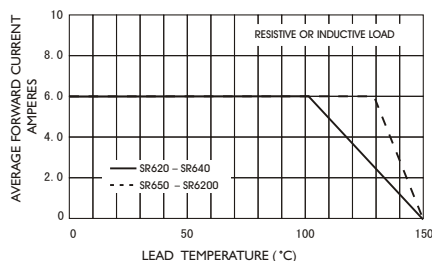


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

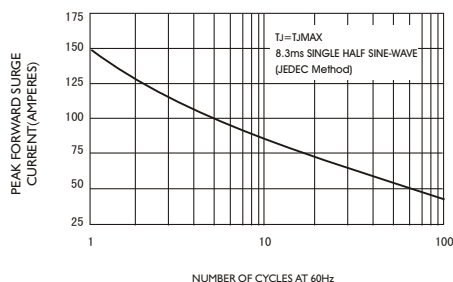


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

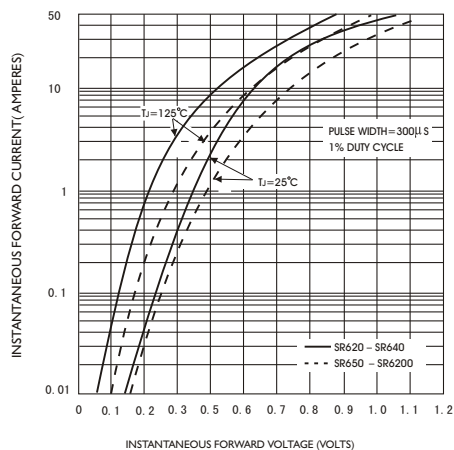


FIG.4-TYPICAL REVERSE CHARACTERISTICS

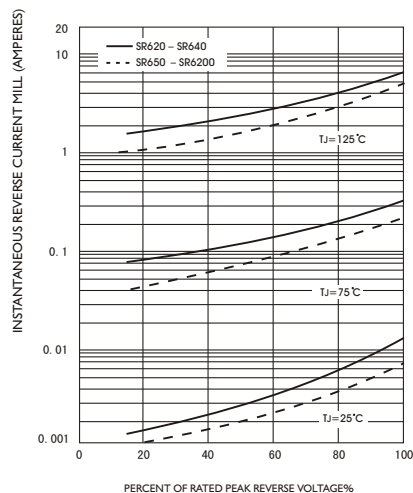


FIG.5-TYPICAL JUNCTION CAPACITANCE

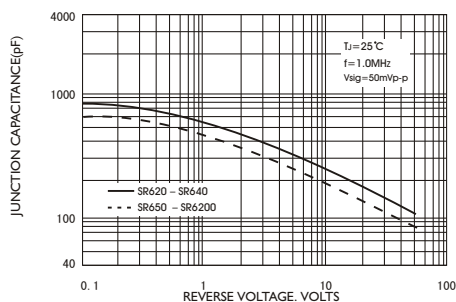


FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE

